

# BCR3PM-12L

# Triac

Low Power Use

REJ03G0301-0200 Rev.2.00 Nov.08.2004

### **Features**

I<sub>T (RMS)</sub>: 3 A
 V<sub>DRM</sub>: 600 V

•  $I_{\text{FGTI}}$ ,  $I_{\text{RGTI}}$ ,  $I_{\text{RGT}}$  : 20 mA (10 mA)<sup>Note5</sup>

• Viso: 2000 V

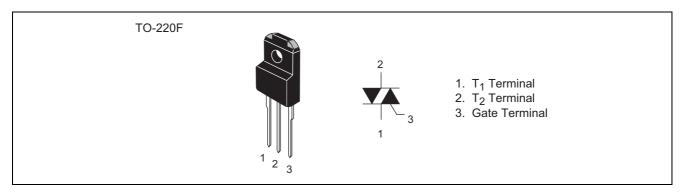
• Insulated Type

• Planar Passivation Type

• UL Recognized: Yellow Card No. E223904

File No. E80271

### **Outline**



### **Applications**

Contactless AC switch, light dimmer, electric blanket, control of household equipment such as electric fan, solenoid driver, small motor control, and other general purpose control applications

# **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	600	V
Non-repetitive peak off-state voltage <sup>Note1</sup>	$V_{DSM}$	720	V

### BCR3PM-12L

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T (RMS)</sub>	3.0	А	Commercial frequency, sine full wave 360° conduction, Tc = 107°C
Surge on-state current	I <sub>TSM</sub>	30	А	60Hz sinewave 1 full cycle, peak value, non-repetitive
I <sup>2</sup> t for fusing	l <sup>2</sup> t	3.7	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	3	W	
Average gate power dissipation	P <sub>G (AV)</sub>	0.3	W	
Peak gate voltage	$V_{GM}$	6	V	
Peak gate current	$I_{GM}$	0.5	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	_	2.0	g	Typical value
Isolation voltage	Viso	2000	V	Ta = 25°C, AC 1 minute, $T_1 \cdot T_2 \cdot G$ terminal to case

Notes: 1. Gate open.

### **Electrical Characteristics**

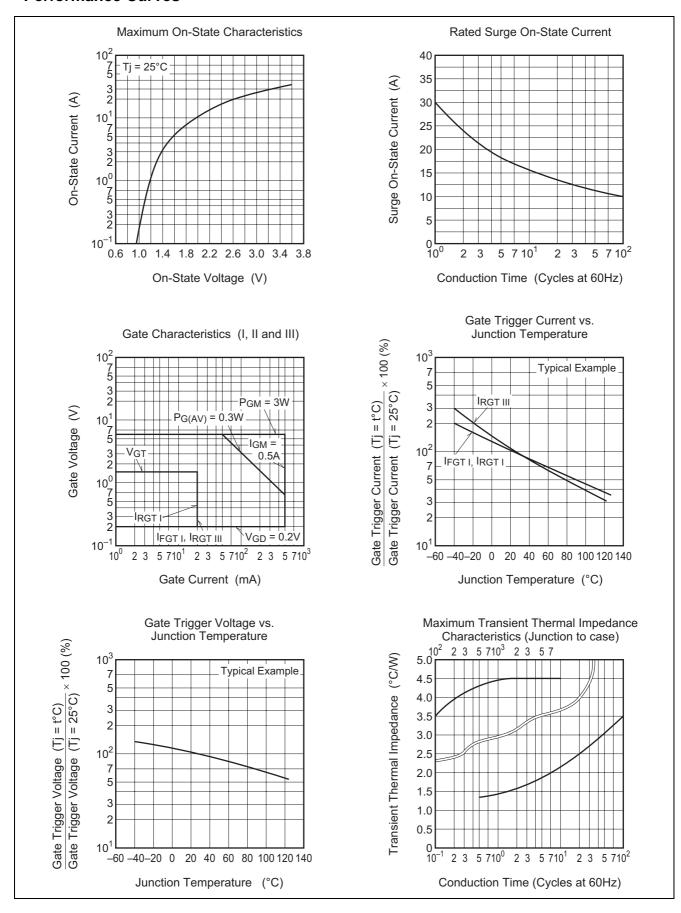
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	I <sub>DRM</sub>	_	_	2.0	mA	Tj = 125°C, V <sub>DRM</sub> applied
On-state voltage		$V_{TM}$	_	_	1.5	V	Tc = 25°C, I <sub>TM</sub> = 4.5 A, Instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	I	$V_{FGTI}$	_	_	1.5	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	$V_{RGTI}$	_	_	1.5	V	$R_G = 330 \Omega$
	III	$V_{RGTIII}$	_	_	1.5	V	
Gate trigger current <sup>Note2</sup>	I	$I_{FGTI}$	_	_	20 <sup>Note5</sup>	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	$I_{RGTI}$	_	_	20 <sup>Note5</sup>	mA	$R_G = 330 \Omega$
	III	$I_{RGTIII}$	_	_	20 <sup>Note5</sup>	mA	
Gate non-trigger voltage		$V_{GD}$	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R <sub>th (j-c)</sub>	_	_	4.5	°C/W	Junction to case <sup>Note3</sup>
Critical-rate of rise of off-star commutating voltage <sup>Note4</sup>	te	(dv/dt)c	5	_	_	V/μs	Tj = 125°C

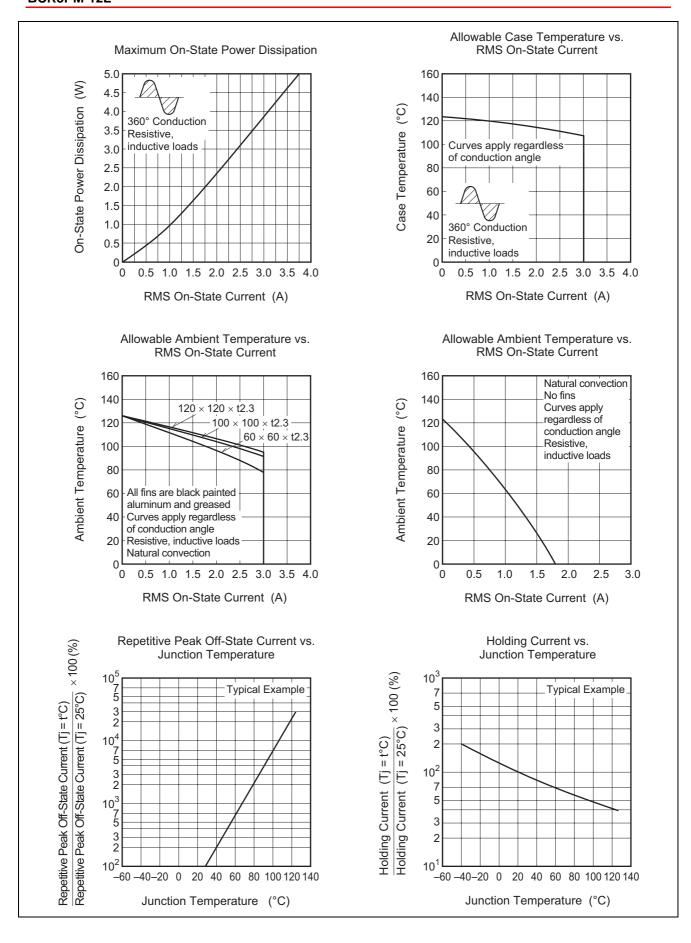
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

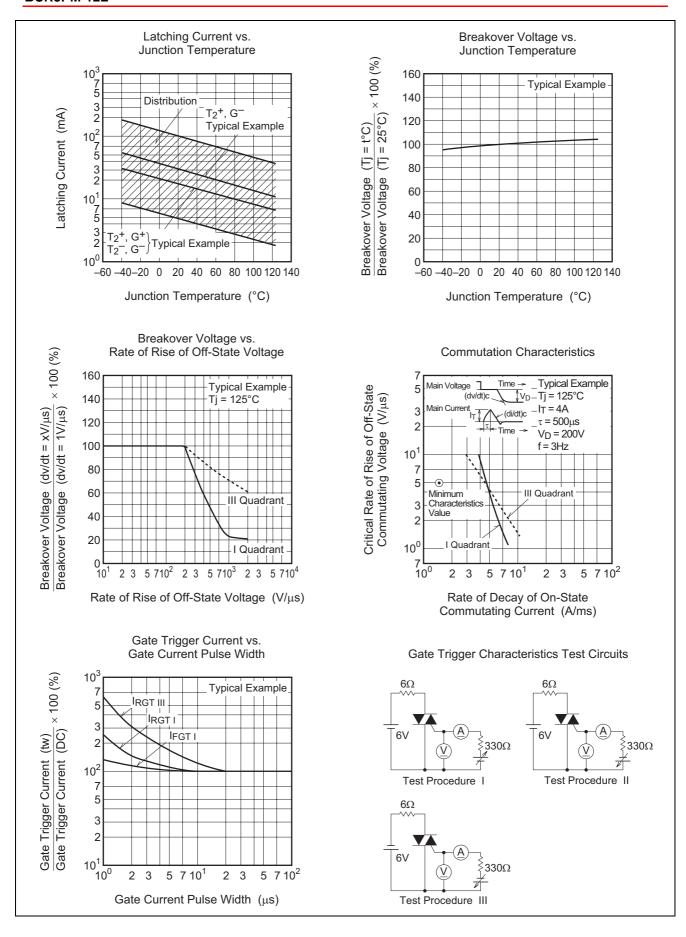
- 3. The contact thermal resistance  $R_{th\ (c\text{-}f)}$  in case of greasing is 0.5°C/W.
- 4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.
- 5. High sensitivity ( $I_{GT} \le 10$  mA) is also available. ( $I_{GT}$  item: 1)

Test conditions	Commutating voltage and current waveforms (inductive load)		
1. Junction temperature  Tj = 125°C	Supply Voltage  →Time		
2. Rate of decay of on-state commutating current (di/dt)c = -1.5 A/ms	Main Current → (di/dt)c → Time		
3. Peak off-state voltage $V_D = 400 \text{ V}$	Main Voltage → Time (dv/dt)c V <sub>D</sub>		

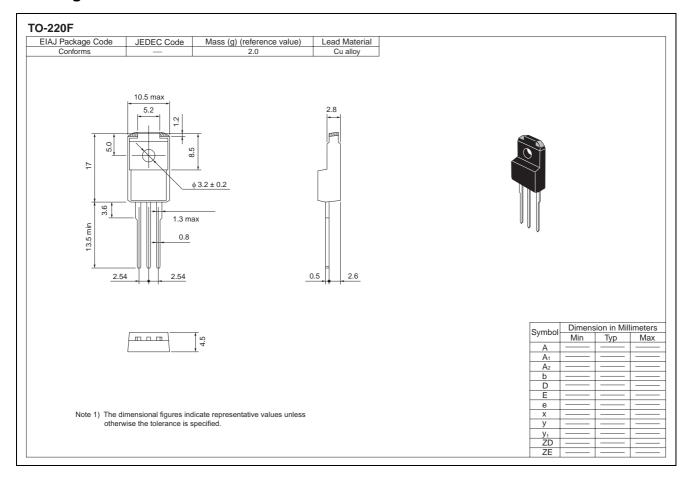
### **Performance Curves**







# **Package Dimensions**



### **Order Code**

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	100	Type name +A	BCR3PM-12LA
Lead form	Plastic Magazine (Tube)	50	Type name +A – Lead forming code	BCR3PM-12LA-A8

Note: Please confirm the specification about the shipping in detail.

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